



ON Semiconductor®

<http://onsemi.com>

2SC3332

Bipolar Transistor 160V, 0.7A, Low $V_{CE(sat)}$ NPN Single NP

Features

- High breakdown voltage
- Excellent h_{FE} linearity
- Wide SOA and highly resistant to breakdown
- Adoption of MBIT process

Specifications

Absolute Maximum Ratings at $T_a=25^{\circ}\text{C}$

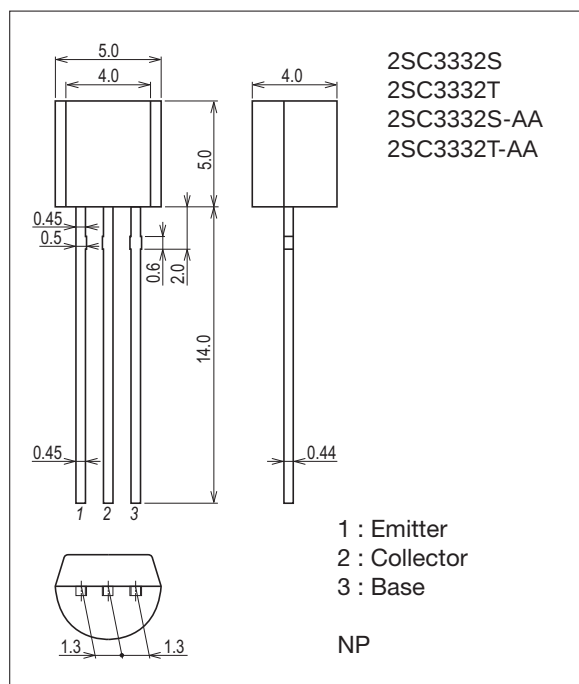
Parameter	Symbol	Conditions	Ratings	Unit
Collector to Base Voltage	V_{CBO}		180	V
Collector to Emitter Voltage	V_{CEO}		160	V
Emitter to Base Voltage	V_{EBO}		6	V
Collector Current	I_C		0.7	A
Collector Current (Pulse)	I_{CP}		1.5	A
Collector Dissipation	P_C		700	mW
Junction Temperature	T_j		150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^{\circ}\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

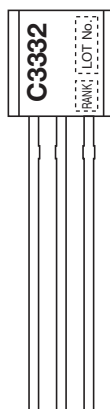
7522-002



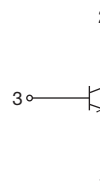
Product & Package Information

- Package : NP
- JEITA, JEDEC : SC-34A, TO-92, TO-226AA, SOT-54
- Minimum Packing Quantity : 1,500 pcs./box, 500pcs./bag

Marking



Electrical Connection



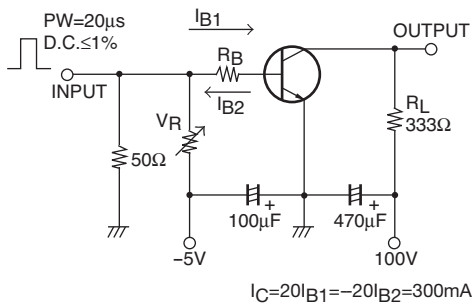
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=120V, I_E=0A$			0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4V, I_C=0A$			0.1	μA
DC Current Gain	h_{FE1}	$V_{CE}=5V, I_C=100mA$	140*		400*	
	h_{FE2}	$V_{CE}=5V, I_C=10mA$	80			
Gain-Bandwidth Product	f_T	$V_{CE}=10V, I_C=50mA$		120		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		8		pF
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=250mA, I_B=25mA$		0.12	0.4	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=250mA, I_B=25mA$		0.85	1.2	V
Collector to Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	180			V
Collector to Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	160			V
Emitter to Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		50		ns
Storage Time	t_{stg}			1000		ns
Fall Time	t_f			60		ns

* : The 2SC3332 is classified by 100mA h_{FE} as follows :

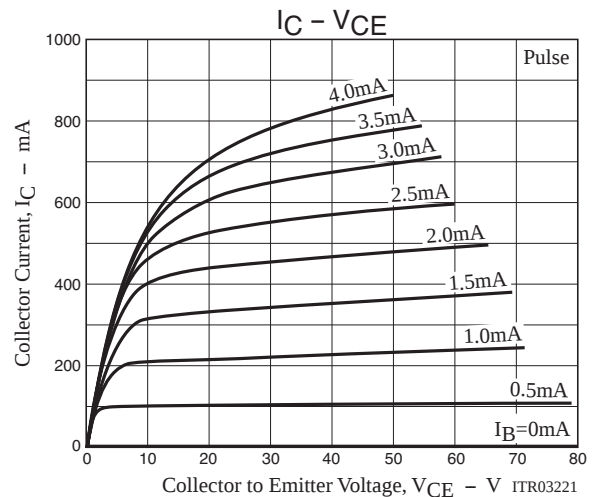
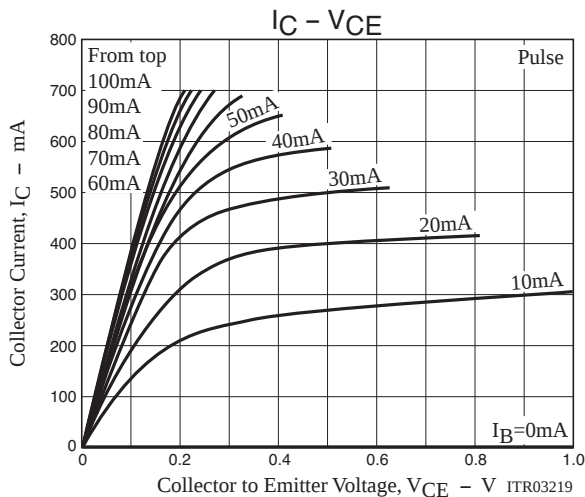
Rank	S	T
h_{FE}	140 to 280	200 to 400

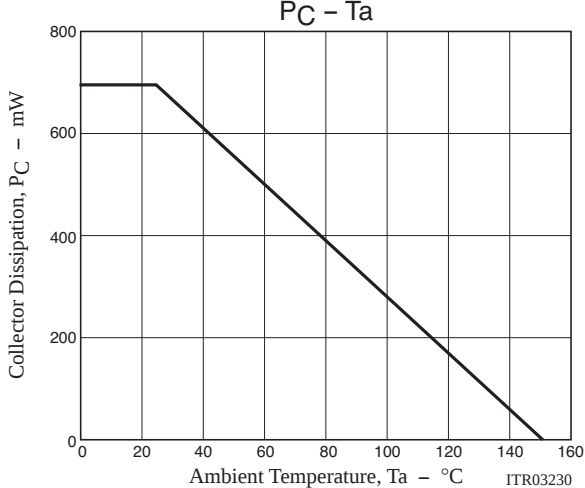
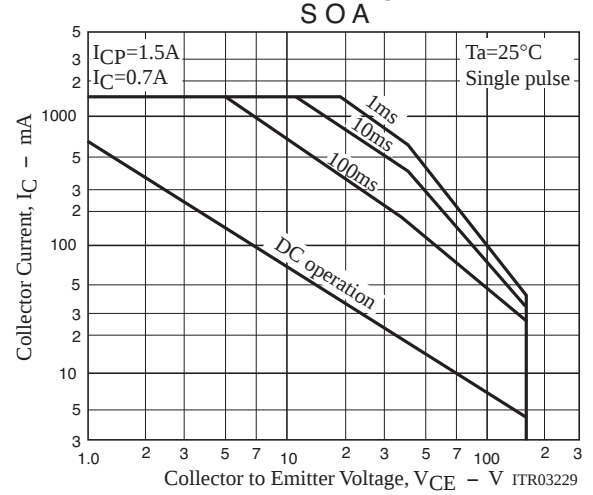
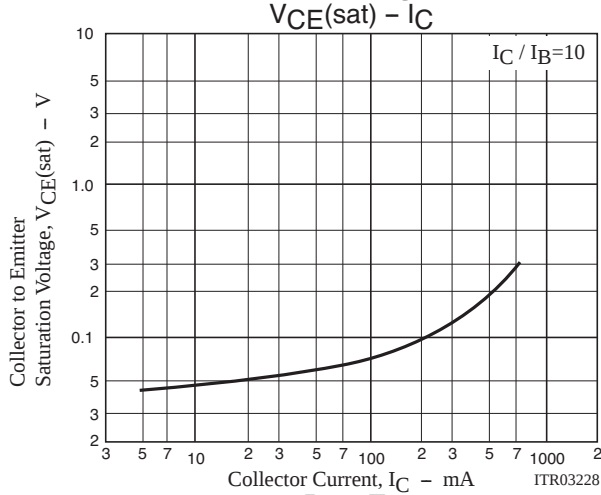
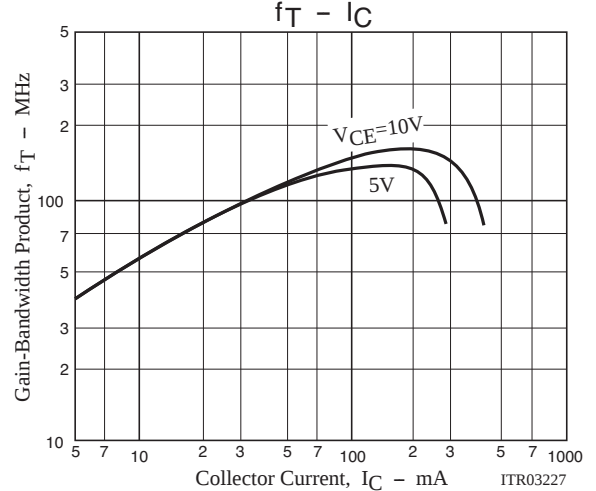
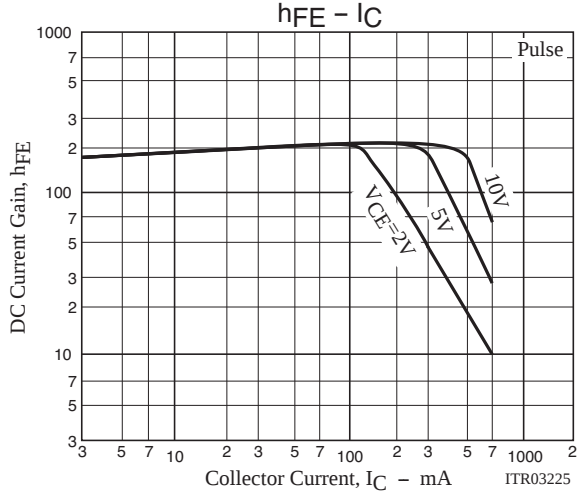
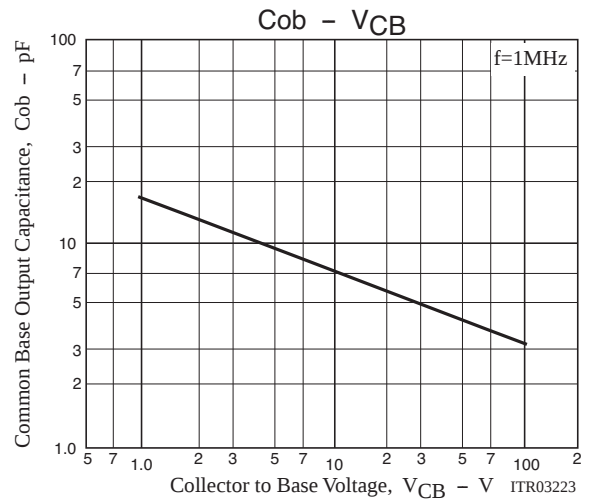
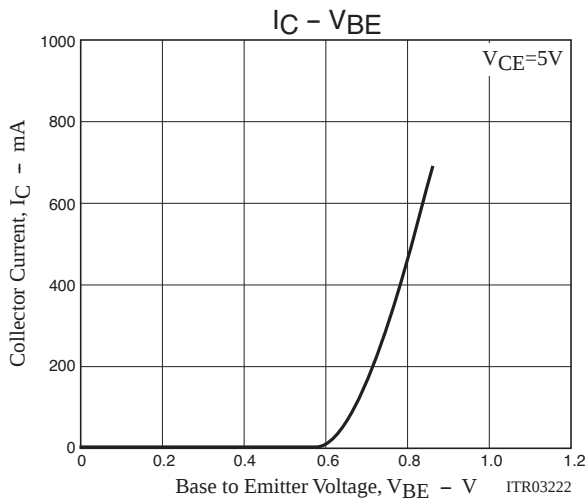
Switching Time Test Circuit



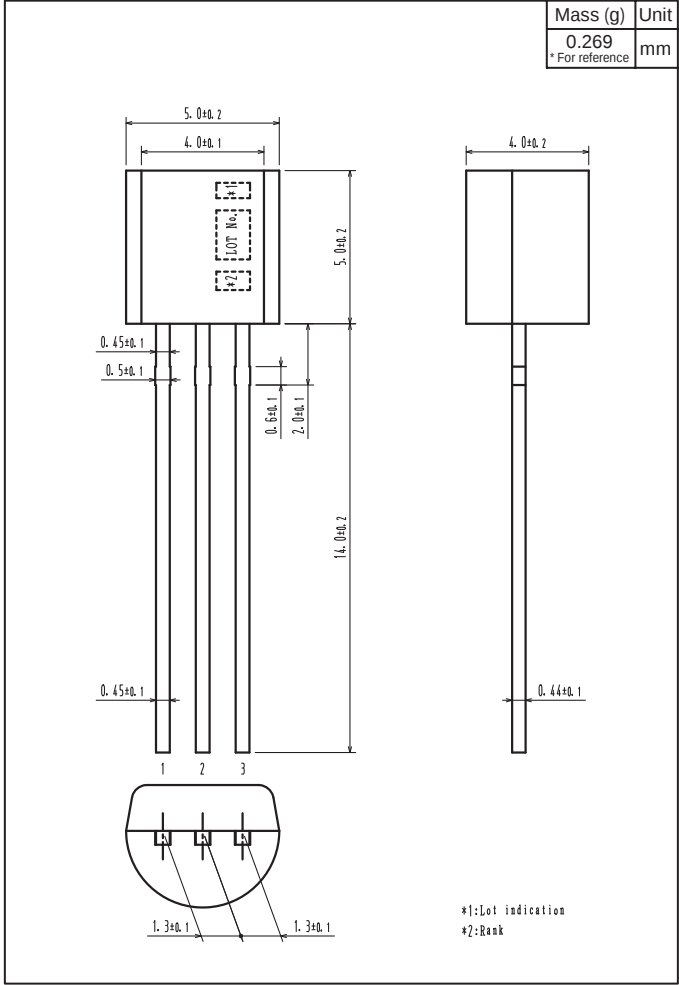
Ordering Information

Device	Package	Shipping	memo
2SC3332S	NP	500pcs./bag	Pb Free
2SC3332T	NP	500pcs./bag	
2SC3332S-AA	NP	1,500pcs./box	
2SC3332T-AA	NP	1,500pcs./box	



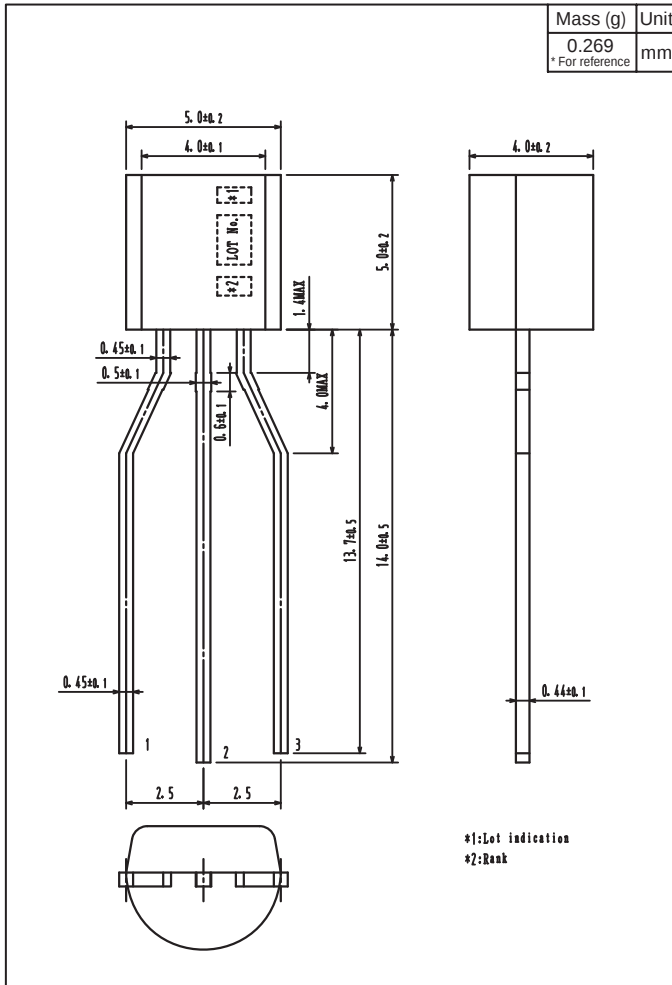


Outline Drawing
2SC3332S, 2SC3332T



Outline Drawing

2SC3332S-AA, 2SC3332T-AA



ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[ON Semiconductor:](#)

[2SC3332S](#) [2SC3332T](#) [2SC3332S-AA](#) [2SC3332T-AA](#) [2SC3332R-AA](#) [2SC3332R](#)

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9